Vishay Semiconductors

High Performance Schottky Rectifier, 3.0 A



www.vishay.com



DO-214AB (SMC)

| PRODUCT SUMMARY | | | |
|----------------------------------|-----------------|--|--|
| Package | DO-214AB (SMC) | | |
| I _{F(AV)} | 3.0 A | | |
| V _R | 15 V | | |
| V _F at I _F | 0.3 V | | |
| I _{RM} | 50 mA at 100 °C | | |
| T _J max. | 125 °C | | |
| Diode variation | Single die | | |
| E _{AS} | 1.5 mJ | | |

FEATURES

- Low forward voltage drop
- Guard ring for enhanced ruggedness and long RoHS compliant reliability
- Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-30BQ015HM3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

| MAJOR RATINGS AND CHARACTERISTICS | | | | | |
|-----------------------------------|--|------------------------|----|--|--|
| SYMBOL | CHARACTERISTICS | CHARACTERISTICS VALUES | | | |
| I _{F(AV)} | Rectangular waveform | 3.0 | A | | |
| V _{RRM} | | 15 | V | | |
| I _{FSM} | t _p = 5 μs sine | 650 | А | | |
| V _F | 1.0 A _{pk} , T _J = 75 °C | 0.30 | V | | |
| TJ | Range | -55 to +125 | °C | | |

| VOLTAGE RATINGS | | | | |
|--------------------------------------|------------------|---------------|-------|--|
| PARAMETER | SYMBOL | VS-30BQ015HM3 | UNITS | |
| Maximum DC reverse voltage | V _R | 15 | - V | |
| Maximum working peak reverse voltage | V _{RWM} | 25 | | |

| ABSOLUTE MAXIMUM RATINGS | | | | | |
|--|--------------------|--|---|--------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | VALUES | UNITS |
| | | 50 % duty cycle at T_L = 83 °C, rectangular waveform | | 3.0 | |
| Maximum average forward current | I _{F(AV)} | 50 % duty cycle at T_L = 78 °C, rectangular waveform | | 4.0 | |
| Maximum peak one cycle non-repetitive surge current | | 5 µs sine or 3 µs rect. pulse | Following any rated load condition and with | 650 | A |
| | IFSM | 10 ms sine or 6 ms rect. pulse | rated V _{RRM} applied | 75 | |
| Non-repetitive avalanche energy | E _{AS} | T _J = 25 °C, I _{AS} = 0.5 A, L = 12 mH | | 1.5 | mJ |
| Repetitive avalanche current | I _{AR} | Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical 0. | | 0.5 | А |

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| ELECTRICAL SPECIFICATIONS | | | | | |
|---------------------------------|--------------------------------|--|---------------------------------------|--------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | VALUES | UNITS |
| Maximum forward voltage drop | V _{FM} ⁽¹⁾ | 3 A | T _J = 25 °C | 0.35 | v |
| | | 6 A | | 0.43 | |
| | | 3 A | T _J = 75 °C | 0.30 | |
| | | 6 A | | 0.38 | |
| Maximum reverse leakage current | I _{RM} | $T_J = 25 \ ^\circ C$ | V _R = Rated V _R | 4 | mA |
| | | T _J = 100 °C | | 50 | |
| Maximum junction capacitance | C _T | $V_{\rm R}$ = 5 $V_{\rm DC}$ (test signal range 100 kHz to 1 MHz), 25 °C | | 1120 | pF |
| Typical series inductance | L _S | Measured lead to lead 5 mm from package body | | 3.0 | nH |
| Maximum voltage rate of change | dV/dt | Rated V _R 10 000 V/µs | | V/µs | |

Note

 $^{(1)}\,$ Pulse width = 300 $\mu s,$ duty cycle = 2 %

| THERMAL - MECHANICAL SPECIFICATIONS | | | | |
|---|----------------------------------|--------------------------------------|-------------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
| Maximum junction temperature range | T _J ⁽¹⁾ | | -55 to +125 | °C |
| Maximum storage temperature range | T _{Stg} | -5 | | |
| Maximum thermal resistance, junction to lead | R _{thJL} ⁽²⁾ | DC operation | 12 | °C/W |
| Maximum thermal resistance, junction to ambient | R _{thJA} | DC operation | 46 | 0/11 |
| Approximate weight | | | 0.24 | g |
| | | | 0.008 | oz. |
| Marking device | | Case style SMC (similar to DO-214AB) | 30 | C |

Notes

(1)

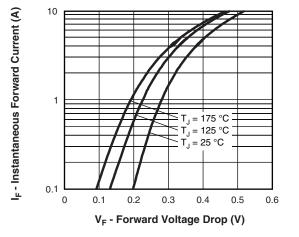
 $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink

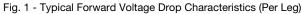
(2) Mounted 1" square PCB

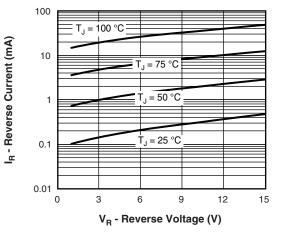


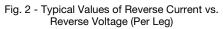
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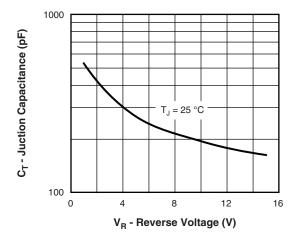
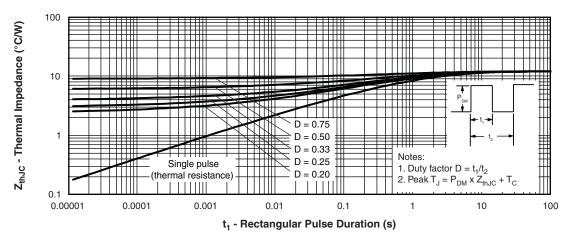
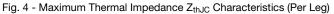


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)





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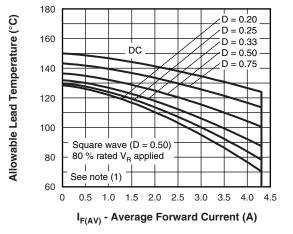


Fig. 5 - Maximum Average Forward Current vs. Allowable Lead Temperature

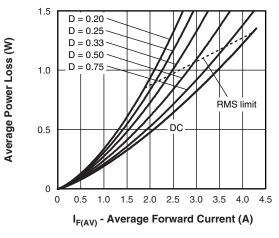


Fig. 6 - Maximum Average Forward Dissipation vs. Average Forward Current

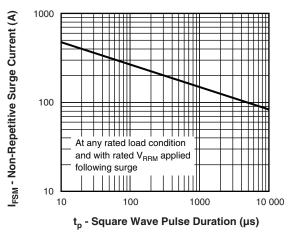


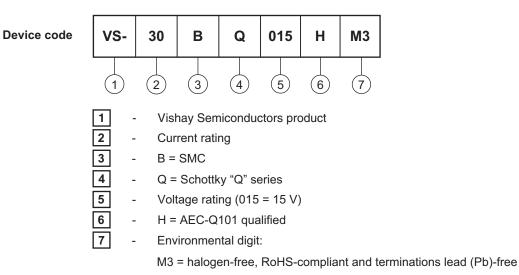
Fig. 7 - Maximum Peak Surge Forward Current vs. Pulse Duration

Note

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ORDERING INFORMATION TABLE



 ORDERING INFORMATION (Example)

 PREFERRED P/N
 PREFERRED PACKAGE CODE
 MINIMUM ORDER QUANTITY
 PACKAGING DESCRIPTION

 VS-30BQ015HM3/9AT
 9AT
 3500
 13" diameter plastic tape and reel

| LINKS TO RELATED DOCUMENTS | | | |
|-------------------------------------|--------------------------|--|--|
| Dimensions www.vishay.com/doc?95402 | | | |
| Part marking information | www.vishay.com/doc?95403 | | |
| Packaging information | www.vishay.com/doc?95404 | | |

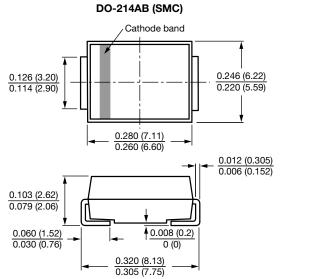


Outline Dimensions

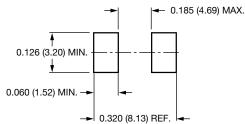
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SMC

DIMENSIONS in inches (millimeters)



Mounting Pad Layout





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